

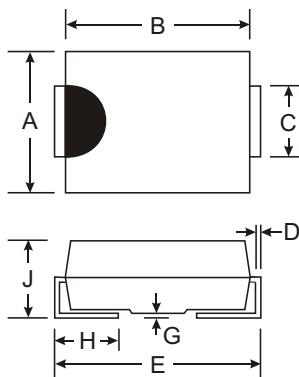
1.0A SURFACE MOUNT SUPER-FAST RECTIFIER

Features

- Glass Passivated Die Construction
- Super-Fast Recovery Time For High Efficiency
- Low Forward Voltage Drop and High Current Capability
- Surge Overload Rating to 30A Peak
- Ideally Suited for Automated Assembly
- Available in Lead Free Finish/RoHS Compliant Version (Note 6)

Mechanical Data

- Case: SMA
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solder Plated Terminal - Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish). Please see Ordering Information, Note 5, on Page 1
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number & Date Code: See Below
- Ordering Information: See Below
- Weight: 0.064 grams (approximate)



SMA		
Dim	Min	Max
A	2.29	2.92
B	4.00	4.60
C	1.27	1.63
D	0.15	0.31
E	4.80	5.59
G	0.10	0.20
H	0.76	1.52
J	2.01	2.30
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

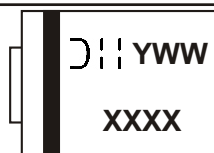
Characteristic	Symbol	ES1A	ES1B	ES1C	ES1D	ES1G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	150	200	400	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	280	V
Average Rectified Output Current @ T _T = 110°C	I _O	1.0					A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	30					A
Forward Voltage Drop @ I _F = 0.6A @ I _F = 1.0A	V _{FM}	0.90 0.98					V
Peak Reverse Current @ T _A = 25°C at Rated DC Blocking Voltage @ T _A = 100°C	I _{RM}	5.0 200					μA
Reverse Recovery Time (Note 1)	t _{rr}	25					ns
Typical Total Capacitance (Note 2)	C _T	10					pF
Typical Thermal Resistance, Junction to Terminal (Note 3)	R _{θJT}	40					°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150					°C

Ordering Information (Note 4)

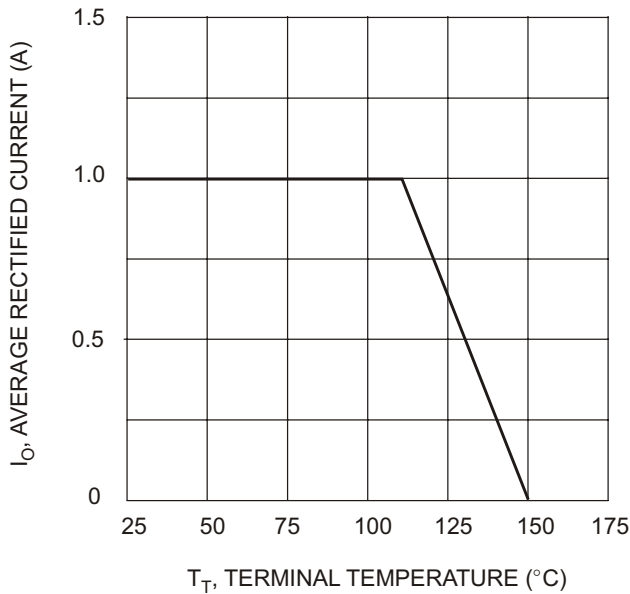
Device*	Packaging	Shipping
ES1x-13	SMA	5000/Tape & Reel

- Notes:
1. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. See figure 5.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Unit mounted on PC board with 5.0 mm² (0.013 mm thick) copper pad as heat sink.
 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>. *x = Device type, e.g. ES1A-13.
 5. For Lead Free Finish/RoHS Compliant version part number, please add "-F" suffix to the part number above. Example: ES1x-13-F.
 6. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.

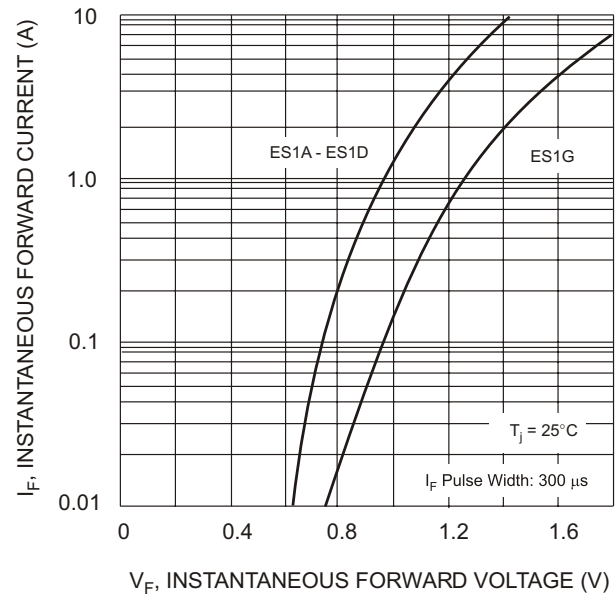
Marking Information



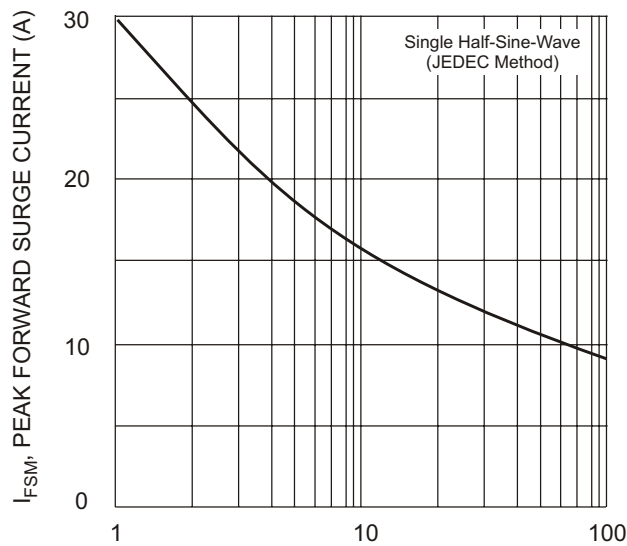
XXXX = Product type marking code, ex. ES1A
 YWW = Manufacturers' code marking
 YWW = Date code marking
 Y = Last digit of year ex: 2 for 2002
 WW = Week code 01 to 52



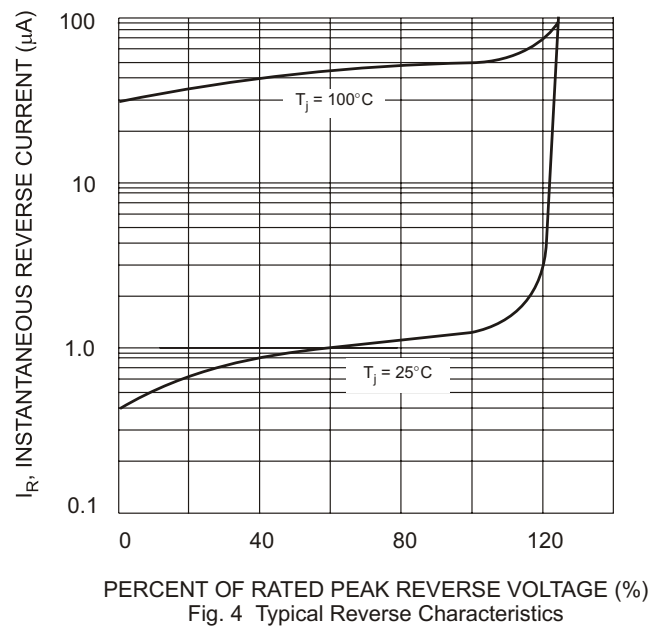
T_T , TERMINAL TEMPERATURE ($^{\circ}\text{C}$)
Fig. 1 Forward Current Derating Curve



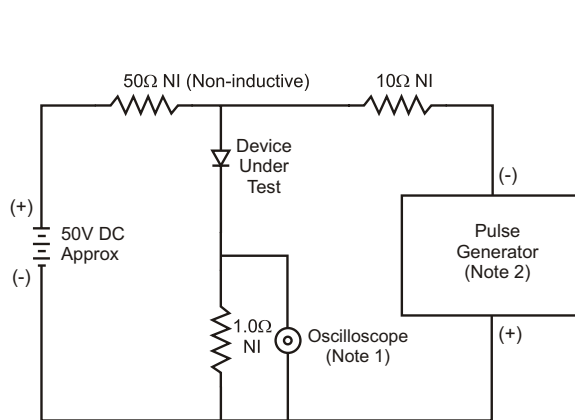
V_F , INSTANTANEOUS FORWARD VOLTAGE (V)
Fig. 2 Typical Forward Characteristics



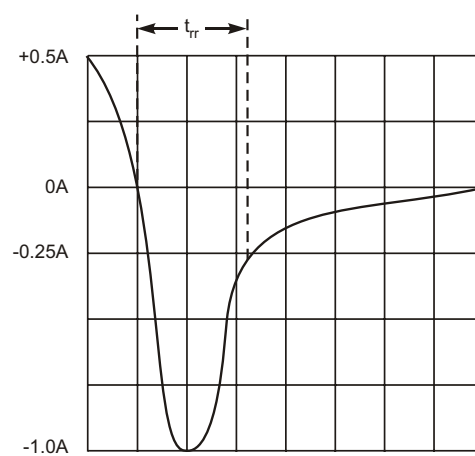
NUMBER OF CYCLES AT 60 Hz
Fig. 3 Surge Current Derating Curve



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)
Fig. 4 Typical Reverse Characteristics



Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0M Ω , 22pF.
2. Rise Time = 10ns max. Input Impedance = 50 Ω .



Set time base for 50/100 ns/cm
Fig. 5 Reverse Recovery Time Characteristic and Test Circuit